

## SPTECH Silicon NPN Power Transistor

MJE15032

**DESCRIPTION**

- Collector-Emitter Sustaining Voltage-  
:  $V_{CEO(SUS)} = 250V$ (Min)
- DC current gain -  
:  $h_{FE} = 50$  (Min) @  $I_C = 0.5 A$   
:  $h_{FE} = 10$  (Min) @  $I_C = 2.0 A$
- Complement to Type MJE15033

**APPLICATIONS**

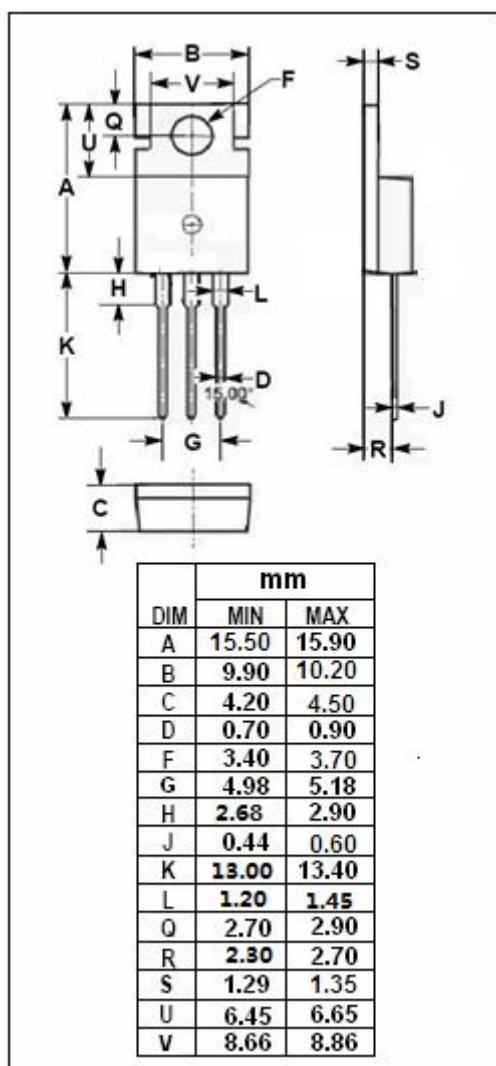
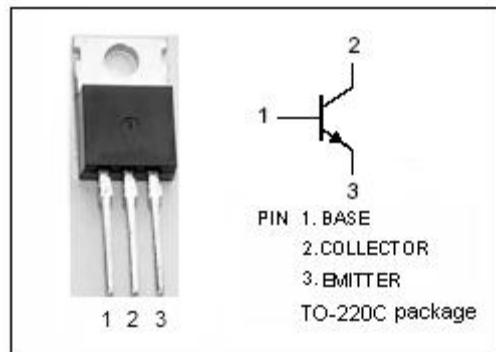
- Designed for use as high-frequency drivers in audio amplifiers.

**ABSOLUTE MAXIMUM RATINGS (Ta=25°C)**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	250	V
$V_{CEO}$	Collector-Emitter Voltage	250	V
$V_{EBO}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current -Continuous	8	A
$I_{CM}$	Collector Current-Peak	16	A
$I_B$	Base Current	2	A
$P_c$	Collector Power Dissipation @ $T_a=25^\circ C$	2	W
	Collector Power Dissipation @ $T_c=25^\circ C$	50	
$T_j$	Junction Temperature	150	°C
$T_{stg}$	Storage Temperature	-65~150	°C

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
$R_{th j-c}$	Thermal Resistance,Junction to Case	2.5	°C/W
$R_{th j-a}$	Thermal Resistance,Junction to Ambient	62.5	°C/W



# SPTECH Product Specification

## SPTECH Silicon NPN Power Transistors

MJE15032

### ELECTRICAL CHARACTERISTICS

T<sub>j</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>CEO(sus)</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 10mA ; I <sub>B</sub> = 0	250		V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 1A ; I <sub>B</sub> = 0.1A		0.5	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 1A ; V <sub>CE</sub> = 5V		1.0	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 150V; I <sub>E</sub> = 0		10	µ A
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0		10	µ A
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 0.5A ; V <sub>CE</sub> = 5V	50		
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 1A ; V <sub>CE</sub> = 5V	50		
h <sub>FE-3</sub>	DC Current Gain	I <sub>C</sub> = 2A ; V <sub>CE</sub> = 5V	10		
f <sub>T</sub>	Current Gain-Bandwidth Product	I <sub>C</sub> = 0.5A; V <sub>CE</sub> = 10V; f <sub>test</sub> = 1.0MHz	30		MHz

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